

自主封測 品質把控 售後保障

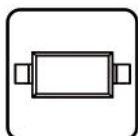
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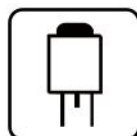
電源管理



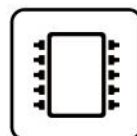
顯示驅動



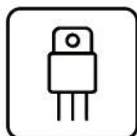
二三極管



LDO穩壓器



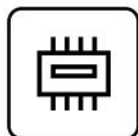
觸摸芯片



MOS管



運算放大器



存儲芯片



MCU



串口通信

P6SMB30CA 30C-TD

產品規格說明書

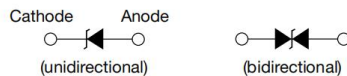
P6SMB Series

Vishay General Semiconductor

Surface-Mount TRANSZORB® Transient Voltage Suppressors



SMB (DO-214AA)



LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS	
V_{WM} (unidirectional)	5.8 V to 459 V
V_{WM} (bidirectional)	5.8 V to 185 V
V_{BR} (unidirectional)	6.8 V to 540 V
V_{BR} (bidirectional)	6.8 V to 220 V
P_{PPM}	600 W
P_D	5.0 W
I_{FSM} (unidirectional only)	100 A
T_J max.	150 °C
Polarity	Unidirectional, bidirectional
Package	SMB (DO-214AA)

DEVICES FOR BIDIRECTION APPLICATIONS

For bidirectional devices use CA suffix (e.g. P6SMB10CA).
Electrical characteristics apply in both directions.

FEATURES

- Low profile package
- Ideal for automated placement
- Glass passivated chip junction
- Available in unidirectional and bidirectional
- 600 W peak pulse power capability with a 10/1000 μ s waveform, repetitive rate (duty cycle): 0.01 %
- Excellent clamping capability
- Very fast response time
- Low incremental surge resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available
 - Automotive ordering code: base P/NHE3 or P/NHM3



TYPICAL APPLICATIONS

Use in sensitive electronics protection against voltage transients induced by inductive load switching and lighting on ICs, MOSFET, signal lines of sensor units for consumer, computer, industrial, and telecommunication.

MECHANICAL DATA

Case: SMB (DO-214AA)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS-compliant, commercial grade

Base P/N-M3 - halogen-free, RoHS-compliant, commercial grade

Base P/NHE3_X - RoHS-compliant and AEC-Q101 qualified

Base P/NHM3_X - halogen-free, RoHS-compliant, and

AEC-Q101 qualified

("_X" denotes revision code e.g. A, B, ...)

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3, M3, HE3, and HM3 suffix meets JESD 201 class 2 whisker test

Polarity: for unidirectional types the band denotes cathode end, no marking on bidirectional types

MAXIMUM RATINGS ($T_A = 25$ °C unless otherwise noted)			
PARAMETER	SYMBOL	VALUE	UNIT
Peak power dissipation with a 10/1000 μ s waveform ⁽¹⁾⁽²⁾ (fig. 1)	P_{PPM}	600	W
Peak pulse current with a 10/1000 μ s waveform ⁽¹⁾	I_{PPM}	See next table	A
Power dissipation on infinite heatsink at $T_A = 50$ °C	P_D	5.0	W
Peak forward surge current 8.3 ms single half sine-wave unidirectional only ⁽²⁾	I_{FSM}	100	A
Operating junction and storage temperature range	T_J, T_{STG}	-65 to +150	°C

Notes

⁽¹⁾ Non-repetitive current pulse, per fig. 3 and derated above $T_A = 25$ °C per fig. 2

⁽²⁾ Mounted on 0.2" x 0.2" (5.0 mm x 5.0 mm) copper pads to each terminal

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)										
PART NUMBER	DEVICE MARKING CODE		BREAKDOWN VOLTAGE V _{BR} AT I _T ⁽¹⁾ (V)		TEST CURRENT I _T (mA)	STAND-OFF VOLTAGE V _{WM} (V)	MAXIMUM REVERSE LEAKAGE AT V _{WM} I _D ⁽³⁾ (μA)	MAXIMUM PEAK PULSE CURRENT I _{PPM} ⁽²⁾ (A)	MAXIMUM CLAMPING VOLTAGE AT I _{PPM} V _C (V)	MAXIMUM TEMPERATURE COEFFICIENT OF V _{BR} (%/°C)
	UNI	BI	MIN.	MAX.						
P6SMB6.8A	6V8A	6V8C	6.45	7.14	10	5.80	1000	57.1	10.5	0.057
P6SMB7.5A	7V5A	7V5C	7.13	7.88	10	6.40	500	53.1	11.3	0.061
P6SMB8.2A	8V2A	8V2C	7.79	8.61	10	7.02	200	49.6	12.1	0.065
P6SMB9.1A	9V1A	9V1C	8.65	9.55	1.0	7.78	50	44.8	13.4	0.068
P6SMB10A	10A	10C	9.50	10.5	1.0	8.55	10	41.4	14.5	0.073
P6SMB11A	11A	11C	10.5	11.6	1.0	9.40	5.0	38.5	15.6	0.075
P6SMB12A	12A	12C	11.4	12.6	1.0	10.2	5.0	35.9	16.7	0.078
P6SMB13A	13A	13C	12.4	13.7	1.0	11.1	5.0	33.0	18.2	0.081
P6SMB15A	15A	15C	14.3	15.8	1.0	12.8	1.0	28.3	21.2	0.084
P6SMB16A	16A	16C	15.2	16.8	1.0	13.6	1.0	26.7	22.5	0.086
P6SMB18A	18A	18C	17.1	18.9	1.0	15.3	1.0	23.8	25.2	0.088
P6SMB20A	20A	20C	19.0	21.0	1.0	17.1	1.0	21.7	27.7	0.090
P6SMB22A	22A	22C	20.9	23.1	1.0	18.8	1.0	19.6	30.6	0.092
P6SMB24A	24A	24C	22.8	25.2	1.0	20.5	1.0	18.1	33.2	0.094
P6SMB27A	27A	27C	25.7	28.4	1.0	23.1	1.0	16.0	37.5	0.096
P6SMB30A	30A	30C	28.5	31.5	1.0	25.6	1.0	14.5	41.4	0.097
P6SMB33A	33A	33C	31.4	34.7	1.0	28.2	1.0	13.1	45.7	0.098
P6SMB36A	36A	36C	34.2	37.8	1.0	30.8	1.0	12.0	49.9	0.099
P6SMB39A	39A	39C	37.1	41.0	1.0	33.3	1.0	11.1	53.9	0.100
P6SMB43A	43A	43C	40.9	45.2	1.0	36.8	1.0	10.1	59.3	0.101
P6SMB47A	47A	47C	44.7	49.4	1.0	40.2	1.0	9.3	64.8	0.101
P6SMB51A	51A	51C	48.5	53.6	1.0	43.6	1.0	8.6	70.1	0.102
P6SMB56A	56A	56C	53.2	58.8	1.0	47.8	1.0	7.8	77.0	0.103
P6SMB62A	62A	62C	58.9	65.1	1.0	53.0	1.0	7.1	85.0	0.104
P6SMB68A	68A	68C	64.6	71.4	1.0	58.1	1.0	6.5	92.0	0.104
P6SMB75A	75A	75C	71.3	78.8	1.0	64.1	1.0	5.8	103	0.105
P6SMB82A	82A	82C	77.9	86.1	1.0	70.1	1.0	5.3	113	0.105
P6SMB91A	91A	91C	86.5	95.5	1.0	77.8	1.0	4.8	125	0.106
P6SMB100A	100A	100C	95.0	105	1.0	85.5	1.0	4.4	137	0.106
P6SMB110A	110A	110C	105	116	1.0	94.0	1.0	3.9	152	0.107
P6SMB120A	120A	120C	114	126	1.0	102	1.0	3.6	165	0.107
P6SMB130A	130A	130C	124	137	1.0	111	1.0	3.4	179	0.107
P6SMB150A	150A	150C	143	158	1.0	128	1.0	2.9	207	0.108
P6SMB160A	160A	160C	152	168	1.0	136	1.0	2.7	219	0.108
P6SMB170A	170A	170C	162	179	1.0	145	1.0	2.6	234	0.108
P6SMB180A	180A	180C	171	189	1.0	154	1.0	2.4	246	0.108
P6SMB200A	200A	200C	190	210	1.0	171	1.0	2.2	274	0.108
P6SMB220A	220A	220C	209	231	1.0	185	1.0	1.8	328	0.108
P6SMB250A	250A	-	237	263	1.0	214	1.0	1.74	344	0.110
P6SMB300A	300A	-	285	315	1.0	256	1.0	1.45	414	0.110
P6SMB350A	350A	-	333	368	1.0	300	1.0	1.24	482	0.110
P6SMB400A	400A	-	380	420	1.0	342	1.0	1.10	548	0.110
P6SMB440A	440A	-	418	462	1.0	376	1.0	1.00	602	0.110
P6SMB480A	480A	-	456	504	1.0	408	1.0	0.91	658	0.110
P6SMB510A	510A	-	485	535	1.0	434	1.0	0.86	698	0.110
P6SMB540A	540A	-	513	567	1.0	459	1.0	0.81	740	0.110

Notes

- (1) Pulse test: t_p ≤ 50 ms
- (2) Surge current waveform per fig. 3 and derate per fig. 2
- (3) For bi-directional types with V_{WM} of 10 V and less, the I_D limit is doubled
- (4) All terms and symbols are consistent with ANSI/IEEE CA62.35
- (5) V_F = 3.5 V at I_F = 50 A (unidirectional only)

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THERMAL CHARACTERISTICS ($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)			
PARAMETER	SYMBOL	VALUE	UNIT
Typical thermal resistance, junction to ambient air ⁽¹⁾	$R_{\theta JA}$	100	$^{\circ}\text{C}/\text{W}$
Typical thermal resistance, junction to lead	$R_{\theta JL}$	20	

Note

⁽¹⁾ Mounted on minimum recommended pad layout

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	VOLTAGE RANGE (V)		PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
		UNI	BI			
P6SMB6.8A-E3/52	0.106	6.8 to 220	6.8 to 220	52	750	7" diameter plastic tape and reel
P6SMB6.8A-M3/52	0.106	6.8 to 540	6.8 to 220	52	750	7" diameter plastic tape and reel
P6SMB6.8A-E3/5B	0.106	6.8 to 220	6.8 to 220	5B	3200	13" diameter plastic tape and reel
P6SMB6.8A-M3/5B	0.106	6.8 to 540	6.8 to 220	5B	3200	13" diameter plastic tape and reel
P6SMB6.8AHE3_B/H ⁽¹⁾	0.106	6.8 to 220	6.8 to 220	H	750	7" diameter plastic tape and reel
P6SMB6.8AHM3_B/H ⁽¹⁾						
P6SMB6.8AHE3_B/I ⁽¹⁾	0.106	6.8 to 220	6.8 to 220	I	3200	13" diameter plastic tape and reel
P6SMB6.8AHM3_B/I ⁽¹⁾						
P6SMB250AHM3_D/H ⁽²⁾	0.106	250 to 540	-	H	750	7" diameter plastic tape and reel
P6SMB250AHM3_D/I ⁽²⁾	0.106	250 to 540	-	I	3200	13" diameter plastic tape and reel

Notes

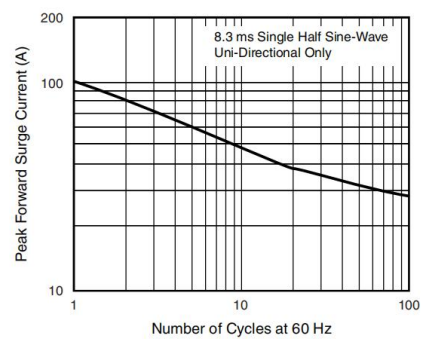
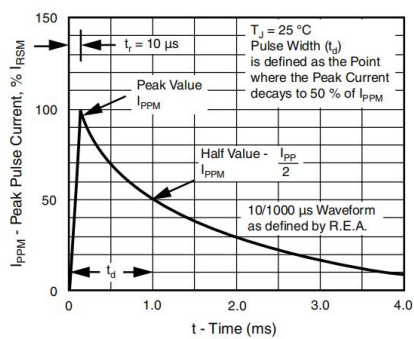
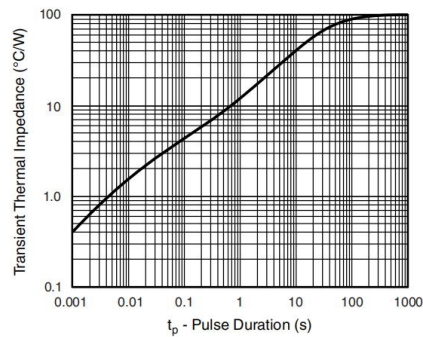
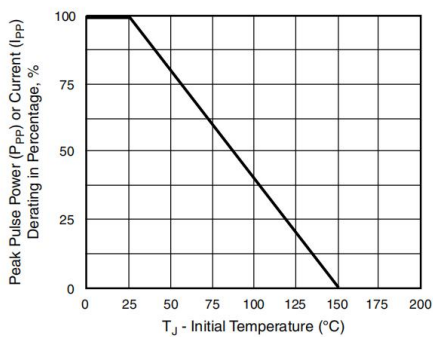
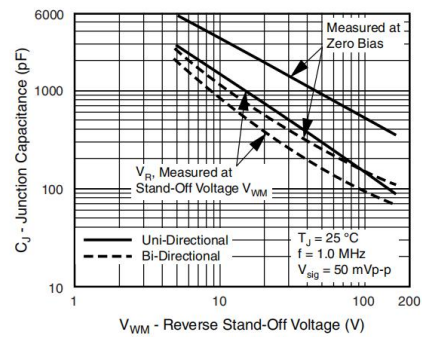
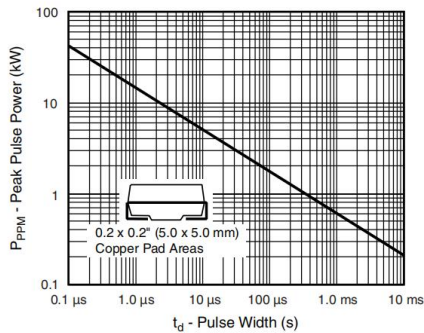
⁽¹⁾ _B is available for P6SMB6.8(C)A to P6SMB220(C)A, AEC-Q101 qualified

⁽²⁾ _D is available for P6SMB250A to P6SMB540A, AEC-Q101 qualified

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RATINGS AND CHARACTERISTICS CURVES ($T_A = 25^\circ\text{C}$ unless otherwise noted)



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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

